

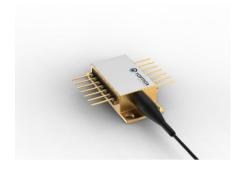
Revision 0.51

25.07.2025

SINGLE FREQUENCY LASER External Cavity Diode Laser



General Product Information	
Product	Application
795 nm mini-ECL	Spectroscopy (Rb D1 line)
with hermetic 14-Pin Butterfly Housing (RoHS compliant)	
including Monitor Diode, Thermoelectric Cooler and Thermistor	
with integrated μ-Isolator and PM Fiber	



Absolute Maximum Ratings Parameter Symbol Unit min typ max °C Storage Temperature T_S -40 85 Operational Temperature at Case °C -40 85 T_C $T_{\rm chip}$ Operational Temperature at Chip °C 50 Forward Current I_F mΑ 270 Reverse Voltage V_{R} V 2 Output Power P_{opt} mW 30 Α TEC Current 1 4 I_{TEC} TEC Voltage $V_{\text{TEC}} \\$ ٧ 4.8

Measurement Conditions / Comments

Stress in excess of one of the Absolute Maximum
Ratings may damage the laser. Please note that a
damaging optical power level may occur although
the maximum current is not reached. These are
stress ratings only, and functional operation at
these or any other conditions beyond those
indicated under Recommended Operational
Conditions is not implied.

Recommended Operational Conditions					
Parameter	Symbol	Unit	min	typ	max
Operational Temperature at Case	T _{case}	°C	-20		65
Operational Temperature at Chip	$T_{\rm chip}$	°C	0		40
Forward Current	I _F	mA			250
Output Power	P _{opt}	mW	5		25

Measurement Conditions / Comments
measured by integrated Thermistor

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Center Wavelength	$\lambda_{\mathbb{C}}$	nm	794	705		
Farget Wavelength			, , ,	795	796	
raiget wavelengtii	$\lambda_{ m T}$	nm		794.98		reached within Tchip = 0 °C 40 °C
inewidth	Δλ	MHz		0.2		measured in the time scale of 1 ms
Mode-hop free Tuning Range	$\Delta \lambda_{tune}$	pm		20		By current tuning, at target wavelength
Output Power	P _{opt}	mW			25	
Sidemode Suppression Ratio	SMSR	dB	30	45		Popt = 25 mW
Temp. Coefficient of Wavelength	dλ/dT	nm/K		0.008		
Current Coefficient of Wavelength	dλ / dl	nm/mA		0.001		
_aser Current	I _{LD}	mA			250	
Slope Efficiency	η	mW/mA		0.2		
Threshold Current	I _{th}	mA		60		
Polarization Extinction Ratio	PER	dB		20		Popt = 25 mW

Monitor Diode			
Parameter	Symbol Unit min	typ max	Measurement Conditions / Comments
Monitor Detector Responsivity	I _{mon} / P _{of} μA/mW	10	5 V

Symbol	Unit	min	typ	max
I _{TEC}	А		0.4	
U_TEC	V		1.5	
P _{loss}	W		0.5	
ΔΤ	Κ			50
	I _{TEC} U _{TEC} P _{loss}	I _{TEC} A U _{TEC} V P _{loss} W	I _{TEC} A U _{TEC} V P _{loss} W	I _{TEC} A 0.4 U _{TEC} V 1.5 P _{loss} W 0.5

Measurement Conditions / Comments
Popt = 25 mW, ΔT = 20 K
Popt = 25 mW, ΔT = 20 K
Popt = 25 mW, ΔT = 20 K
Popt = 25 mW, ΔT = Tcase - Tchip

Symbol	Unit	min	typ	max
R	kΩ		10	
b			3892	
А		1.	1293 x 10 ⁻¹	3
В		2.	3410 x 10	4
С		8.	7755 x 10 ⁻¹	8
	R b A B	R kΩ b A B	R kΩ b A 1. B 2.	R kΩ 10 b 3892 A 1.1293 x 10 ⁻³ B 2.3410 x 10 ⁻³

Measurement Conditions / Comments
Tchip = 25 °C
$R_1/R_2 = e^{\beta}(1/T_1 - 1/T_2)$ at Tchip = 0 50 °C
$1/T = A + B(\ln R) + C(\ln R)^3$
T: Temperature in Kelvin
R: resistance at T in Ω

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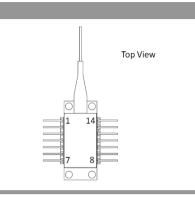
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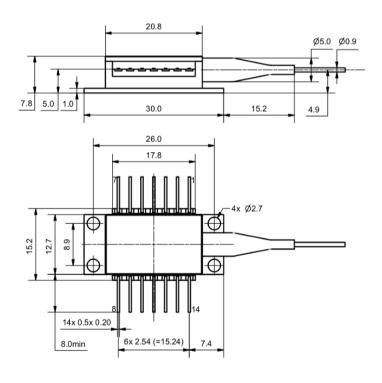
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Pin Assignment	
1 Thermoelectric Cooler (+)	14 Thermoelectric Cooler (-)
2 Thermistor	13 Case
3 Photo Diode Anode	12 not connected
4 Photo Diode Cathode	11 Laser Diode Cathode
5 Thermistor	10 Laser Diode Anode
6 not connected	9 not connected
7 not connected	8 not connected



Package Drawings





* For properties of fiber pigtall and connector type please see P/N specification sheet

AIZ-16-0222-1415

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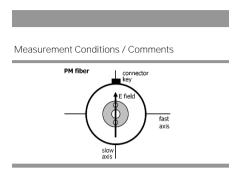
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Parameter	
PM Fiber	900 / 125 / 5.5 μm, UV/Polyester-elastomer Coating (I = 1 +/-0.1 m)
Connector	FC/APC (narrow key / 2mm)



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Unpacking, Installation and Laser Safety

contribute to a long lifetime of the diode.

Unpacking the laser diodes should only be done at electrostatic safe workstations (EPA). Though protection against electro static discharge (ESD) is implemented in the laser package, charges may occur at surfaces. Please store this product in its original package at a dry, clean place until final use. During device installation, ESD protection has to be maintained.





A laser diode is sensitive against optical feedback, so an optical isolator may be required in order to avoid any disturbance of the emission spectrum. Operating at moderate temperatures on proper heat sinks will



AVOID FYF OR SKIN EXPOSUR DIRECT OR SCATTERED RADIATIO CLASS 4 LASER PRODUCT WAVELENGTH 795 nm

Avoid direct and/or indirect exposure to the free running beam. Collimating and focussing the free running beam with optics as common in optical instruments will increase threat to the human eye.

Each laser diode will come with an individual test protocol verifying the parameters given in this document.





Performance figures, data and any illustrative material provided in this specification are typical and must be specifically confirmed in writing by eagleyard Photonics before they become applicable to any particular order or contract. In accordance with the eagleyard Photonics policy of continuous improvement specifications may change without notice.

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